NSN 5961-01-089-0776

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-089-0776 **Inclosure Material:** Metal **Overall Length:** Between 1.360 inches and 1.375 inches **Overall Height:** 0.712 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 collector to base voltage/static/emitter open and 9.0 emitter to base voltage, static, collector open and 400.0 collector-to-emitter, substaining voltage, base open-circuited **Current Rating Per Characteristic:** Between 5.00 amperes source cutoff current and 15.00 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: Yes - demil/mli